NSN 5961-01-058-4789

A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-058-4789 **Inclosure Material:** Metal **Overall Length:** 0.340 inches **Function For Which Designed:** Rectifier **Mounting Facility Quantity: Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Thread Size:** 0.112 inches **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 75.0 working peak reverse voltage, peak total value and 75.0 reverse voltage, instantaneous **Current Rating Per Characteristic:** 20.00 amperes forward current, average absolute **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Test Data Document:** 99971-7536582 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Thread Series Designator:** Unc **Terminal Type And Quantity:** 1 solder stud and 1 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: